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## Inclosure Material:

Plastic

**Overall Length:** 

0.600 inches

# **Overall Height:**

0.190 inches

# **Overall Width:**

0.410 inches

# Mounting Facility Quantity:

1

### Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-220

#### **Mounting Method:**

## Unthreaded hole

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

500.0 collector to base voltage, dc and 400.0 collector-to-emitter voltage, instantaneous and 5.0 emitter to base voltage, dc

### **Current Rating Per Characteristic:**

1.00 amperes source cutoff current and 0.60 amperes source cutoff current

### Power Rating Per Characteristic:

40.0 watts small-signal input power, common-collector preset

### Transfer Ratio:

150.0 static forward current transfer ratio, common-emitter

### Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: npn

### **Terminal Type And Quantity:**

3 pin

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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